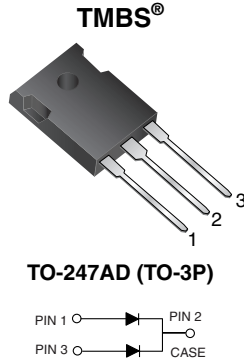


Dual High-Voltage Trench MOS Barrier Schottky Rectifier

Ultra Low $V_F = 0.456\text{ V}$ at $I_F = 10\text{ A}$



FEATURES

- Trench MOS Schottky technology
- Low forward voltage drop, low power losses
- High efficiency operation
- Low thermal resistance
- Solder dip 260 °C, 40 s
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC



RoHS
COMPLIANT

TYPICAL APPLICATIONS

For use in high frequency inverters, switching power supplies, freewheeling diodes, OR-ing diode, dc-to-dc converters and reverse battery protection.

PRIMARY CHARACTERISTICS

| | |
|------------------------------|----------|
| $I_{F(AV)}$ | 2 x 30 A |
| V_{RRM} | 100 V |
| I_{FSM} | 350 A |
| V_F at $I_F = 30\text{ A}$ | 0.657 V |
| T_J max. | 150 °C |

MECHANICAL DATA

Case: TO-247AD (TO-3P)

Epoxy meets UL 94V-0 flammability rating

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD22-B102

E3 suffix for consumer grade, meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS ($T_A = 25\text{ °C}$ unless otherwise noted)

| PARAMETER | SYMBOL | V60100P | UNIT |
|--|----------------|---------------|------------------|
| Maximum repetitive peak reverse voltage | V_{RRM} | 100 | V |
| Maximum average forward rectified current (Fig. 1) | $I_{F(AV)}$ | 60 30 | A |
| Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode | I_{FSM} | 350 | A |
| Peak repetitive reverse current per diode at $t_p = 2\text{ }\mu\text{s}$, 1 kHz | I_{RRM} | 1.0 | A |
| Voltage rate of change (rated V_R) | dV/dt | 10 000 | V/ μs |
| Operating junction and storage temperature range | T_J, T_{STG} | - 40 to + 150 | °C |



| ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted) | | | | | | |
|--|---|---|-----------------|-------------------------|----------------|----------|
| PARAMETER | TEST CONDITIONS | | SYMBOL | TYP. | MAX. | UNIT |
| Breakdown voltage | I _R = 1.0 mA | T _J = 25 °C | V _{BR} | 100 (minimum) | - | V |
| Instantaneous forward voltage per diode ⁽¹⁾ | I _F = 10 A I _F = 15 A I _F = 30 A | T _J = 25 °C | V _F | 0.518 0.576 0.730 | - - 0.79 | V |
| | I _F = 10 A I _F = 15 A I _F = 30 A | T _J = 125 °C | | 0.456 0.531 0.657 | - - 0.70 | |
| Reverse current per diode ⁽²⁾ | V _R = 80 V | T _J = 25 °C T _J = 125 °C | I _R | 34.6 9.5 | - - | μA mA |
| | V _R = 100 V | T _J = 25 °C T _J = 125 °C | | 82.0 19.2 | 800 45 | μA mA |

Notes:

- (1) Pulse test: 300 μs pulse width, 1 % duty cycle
- (2) Pulse test: Pulse width ≤ 40 ms

| THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted) | | | |
|---|------------------|---------|------|
| PARAMETER | SYMBOL | V60100P | UNIT |
| Typical thermal resistance per diode | R _{θJC} | 1.5 | °C/W |

| ORDERING INFORMATION (Example) | | | | |
|--------------------------------|-----------------|------------------------|---------------|---------------|
| PREFERRED P/N | UNIT WEIGHT (g) | PREFERRED PACKAGE CODE | BASE QUANTITY | DELIVERY MODE |
| V60100P-E3/45 | 6.12 | 45 | 30/tube | Tube |

RATINGS AND CHARACTERISTICS CURVES

(T_A = 25 °C unless otherwise noted)

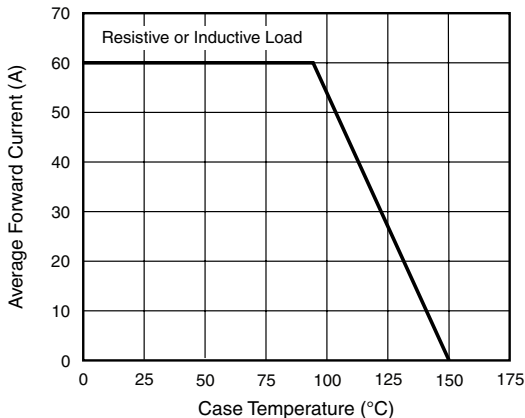


Figure 1. Forward Current Derating Curve

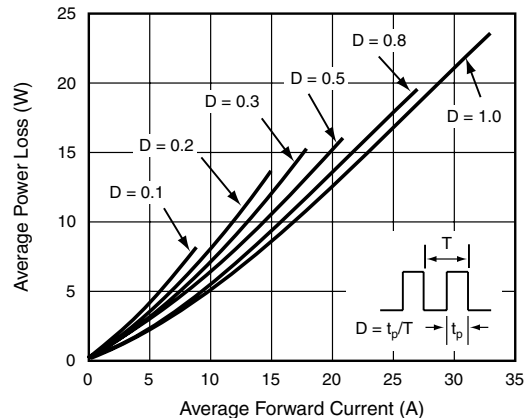


Figure 2. Forward Power Loss Characteristics Per Diode

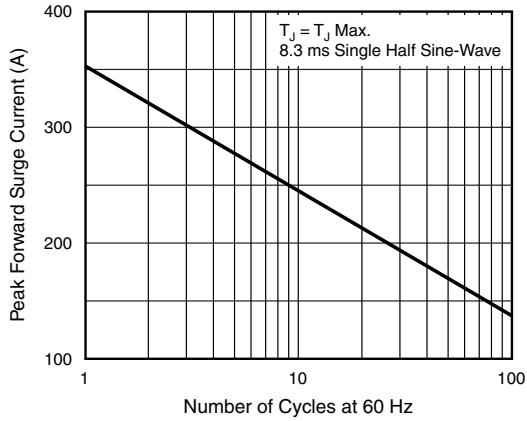


Figure 3. Maximum Non-Repetitive Peak Forward Surge Current Per Diode

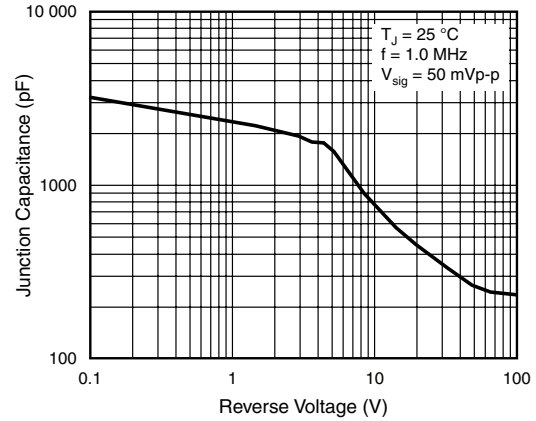


Figure 6. Typical Junction Capacitance Per Diode

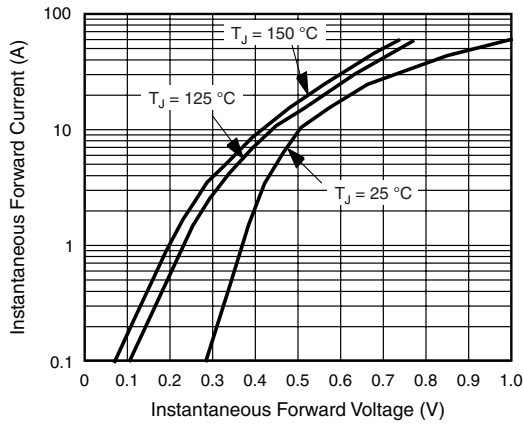


Figure 4. Typical Instantaneous Forward Characteristics Per Diode

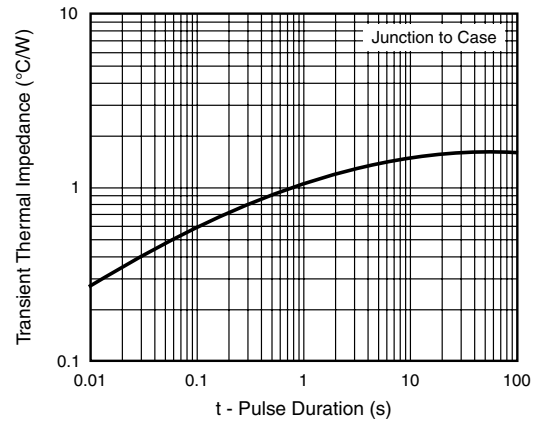


Figure 7. Typical Transient Thermal Impedance Per Diode

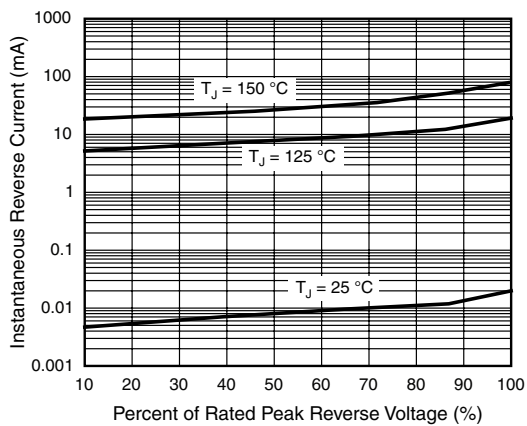
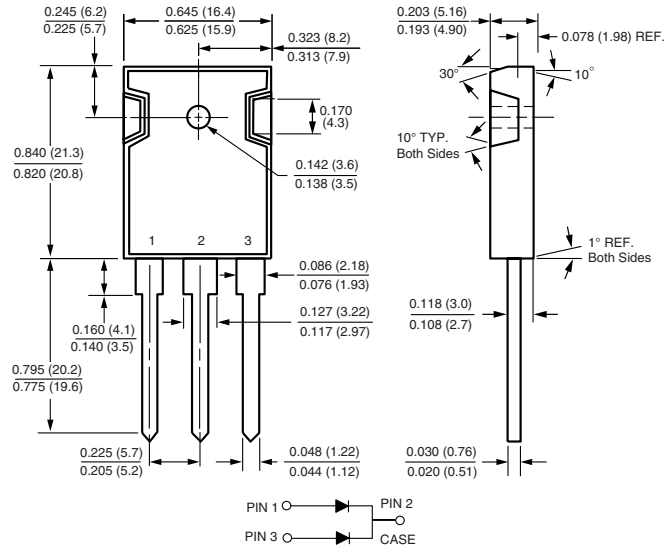


Figure 5. Typical Reverse Characteristics Per Diode

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

TO-247AD (TO-3P)





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